

FM10L45-T7B

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FM10L45-T7B

10.0A Surface Mount Schottky Barrier Rectifiers-45V

Features

- High Current Density Schottky.
- Low Forward Voltage Drop
- Excellent High Temperature Stability
- Soft, Fast Switching Capability
- Lead Free Finish,RoHS Compliant
- Suffix "-H" indicates Halogen free parts, ex. FM10L45-T7B-H.

Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- Case : TO-277B ,molded Plastic
- Terminals: Matte Tin Finish Annealed Over Copper Leadframe. Solderable Per MIL-STD-202,Method 208
- Weight:0.1 grams(approx)

Maximum ratings (AT $T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	FM10L45-T7B	Unit
DC Blocking Voltage	V_{DC}	45	V
Working Peak Reverse Voltage	V_{RWM}		
Repetitive Peak Reverse Voltage	V_{RRM}		
RMS Reverse Voltage	V_{RMS}	31.5	V
Average Forward Rectified Current	$I_{F(AV)}$	10.0	A
Peak Forward Surge Current,8.3ms single half sine-wave($T_A=25^{\circ}\text{C}$)	I_{FSM}	180	A
Operating junction temperature range	T_J	-55 to +150	$^{\circ}\text{C}$
Storage temperature range	T_{STG}	-55 to +150	$^{\circ}\text{C}$

Electrical Characteristics (AT $T_A=25^{\circ}\text{C}$ unless otherwise noted)

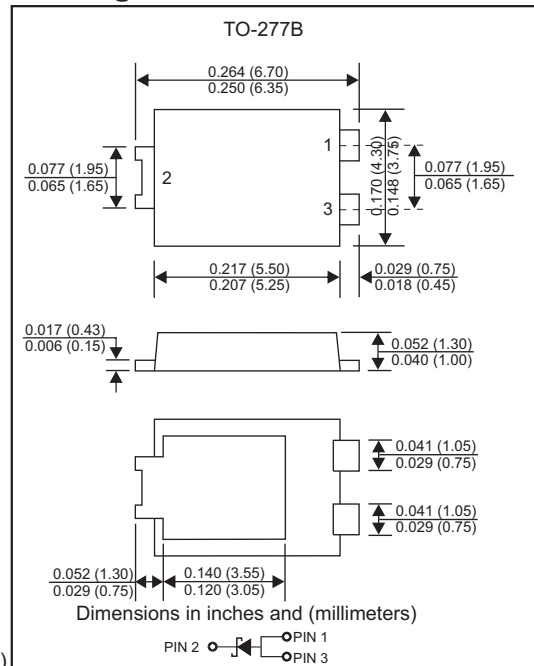
Parameter	Test Conditions	Symbol	MIN.	TYP.	MAX.	Unit
Reverse Breakdown Voltage	$I_R=0.5\text{mA}, T_J=25^{\circ}\text{C}$	V_B	45	-	-	V
Forward voltage	$I_F=1.0\text{A}, T_J=25^{\circ}\text{C}$	V_F	-	0.28	-	V
	$I_F=2.0\text{A}, T_J=25^{\circ}\text{C}$		-	0.32	-	
	$I_F=3.0\text{A}, T_J=25^{\circ}\text{C}$		-	0.34	-	
	$I_F=5.0\text{A}, T_J=25^{\circ}\text{C}$		-	0.38	-	
	$I_F=10.0\text{A}, T_J=25^{\circ}\text{C}$		-	0.46	0.48	
	$I_F=1.0\text{A}, T_J=125^{\circ}\text{C}$		-	0.16	-	
	$I_F=2.0\text{A}, T_J=125^{\circ}\text{C}$		-	0.21	-	
	$I_F=3.0\text{A}, T_J=125^{\circ}\text{C}$		-	0.25	-	
	$I_F=5.0\text{A}, T_J=125^{\circ}\text{C}$		-	0.31	-	
Reverse current	$V_R=45\text{V}, T_J=25^{\circ}\text{C}$	I_R	-	0.1	0.5	mA
	$V_R=45\text{V}, T_J=125^{\circ}\text{C}$		-	60	-	

Thermal Characteristics

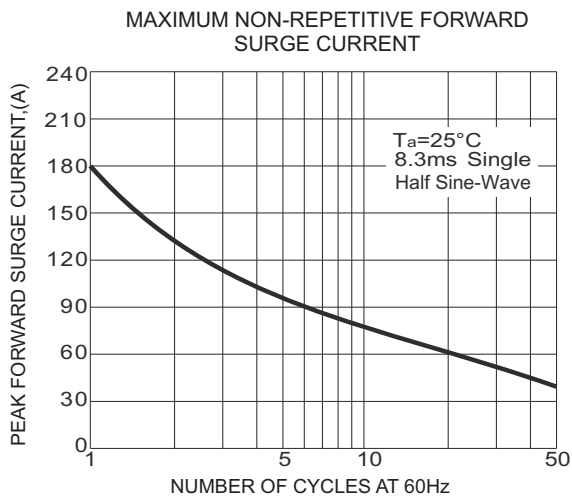
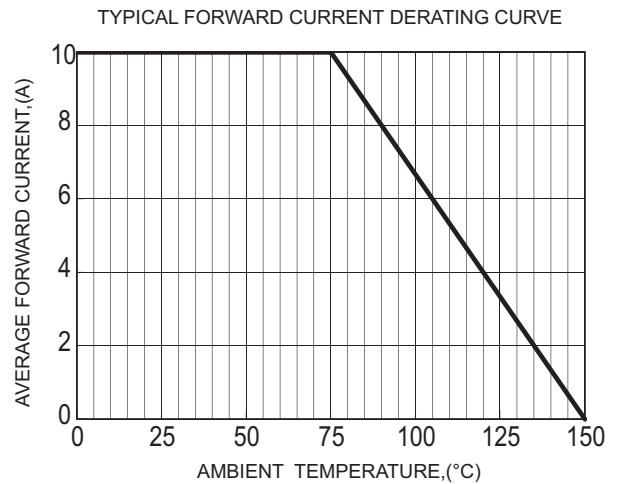
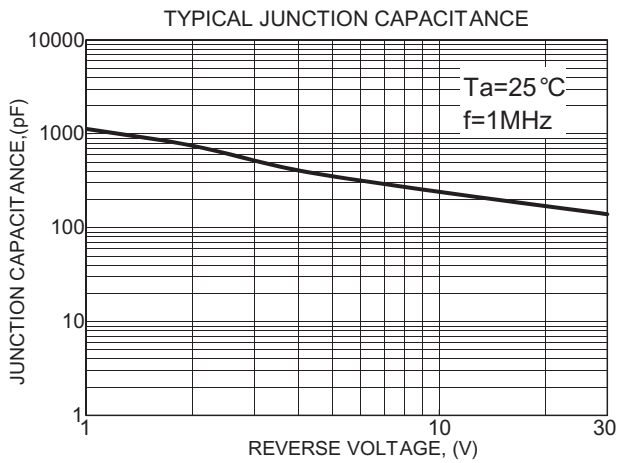
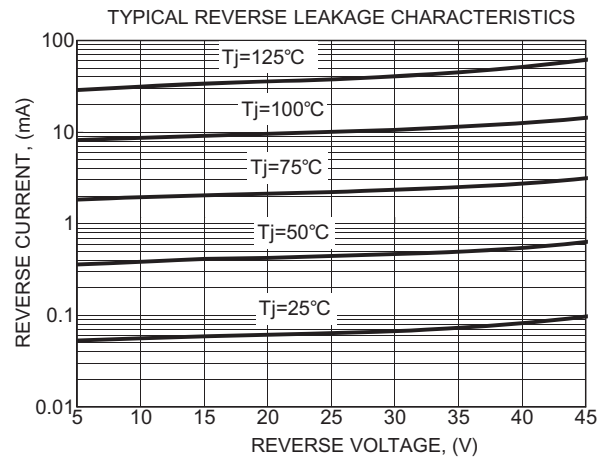
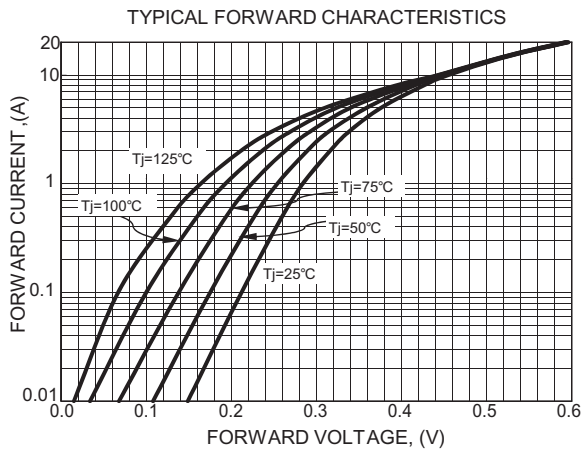
Parameter	Symbol	FM10L45-T7B	Unit
Typical thermal resistance junction to ambient (Note 1)	$R_{\theta JA}$	17	$^{\circ}\text{C}/\text{W}$
Typical thermal resistance junction to case (Note 1)	$R_{\theta JC}$	3	$^{\circ}\text{C}/\text{W}$

Note 1: Mounted on FR-4 PCB copper pad area. Cathode pad dimensions 4.95mm x 3.4mm. Anode pad dimensions 1.55mm x 5.0mm.

Package outline



Rating and characteristic curves



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Pinning information

Pin	Simplified outline	Symbol
PIN 1 anode PIN 3 anode PIN 2 cathode		

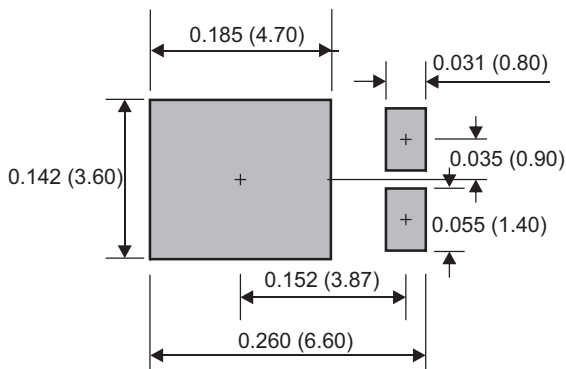
Marking



Note 1: YMDX= Date code

Suggested solder pad layout

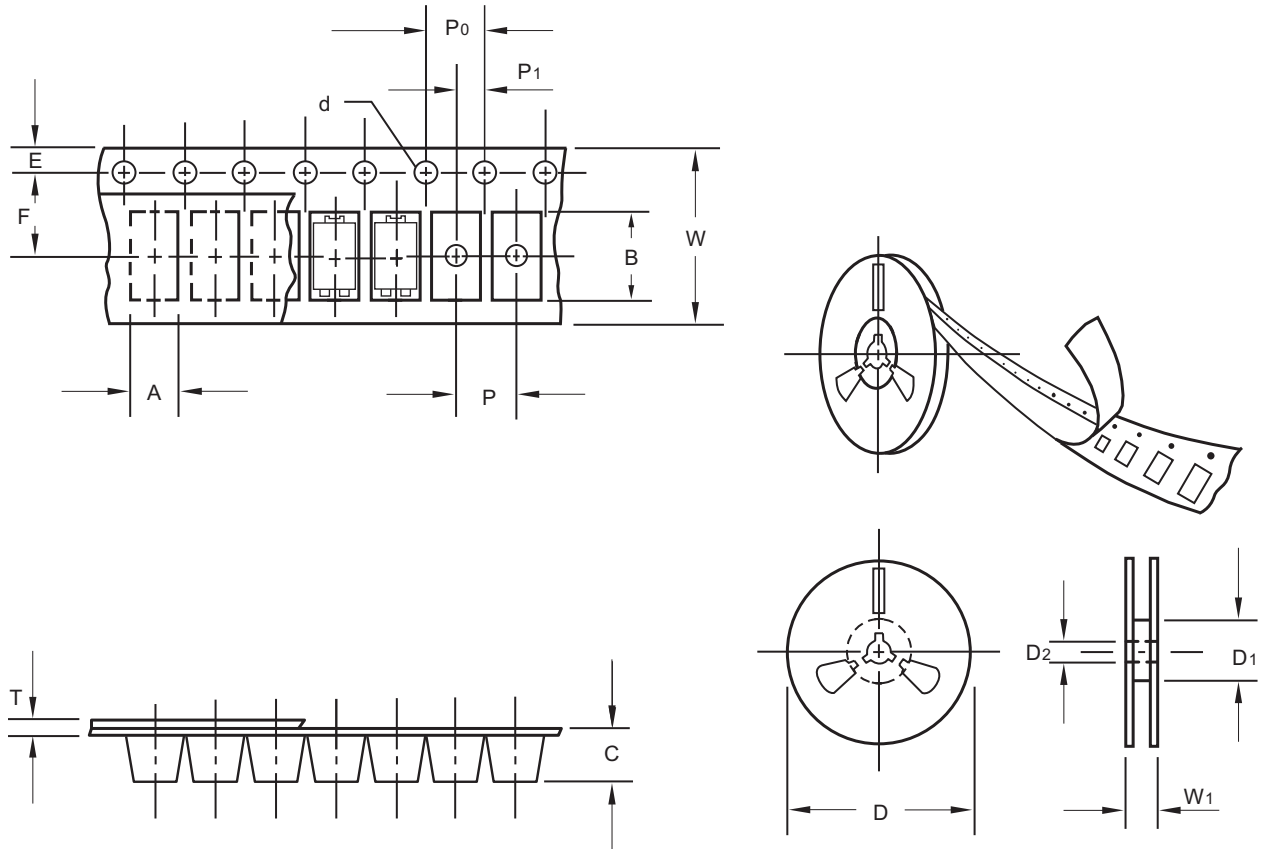
TO-277B



Dimensions in inches and (millimeters)

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Packing information



unit:mm

Item	Symbol	Tolerance	TO-277B
Carrier width	A	0.1	4.54
Carrier length	B	0.1	6.80
Carrier depth	C	0.1	1.33
Sprocket hole	d	0.1	1.50
13" Reel outside diameter	D	2.0	330.00
13" Reel inner diameter	D1	min	50.00
7" Reel outside diameter	D	2.0	178.00
7" Reel inner diameter	D1	min	62.00
Feed hole diameter	D2	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	5.50
Punch hole pitch	P	0.1	8.00
Sprocket hole pitch	P0	0.1	4.00
Embossment center	P1	0.1	2.00
Overall tape thickness	T	0.1	0.23
Tape width	W	0.3	12.00
Reel width	W1	1.0	18.00

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

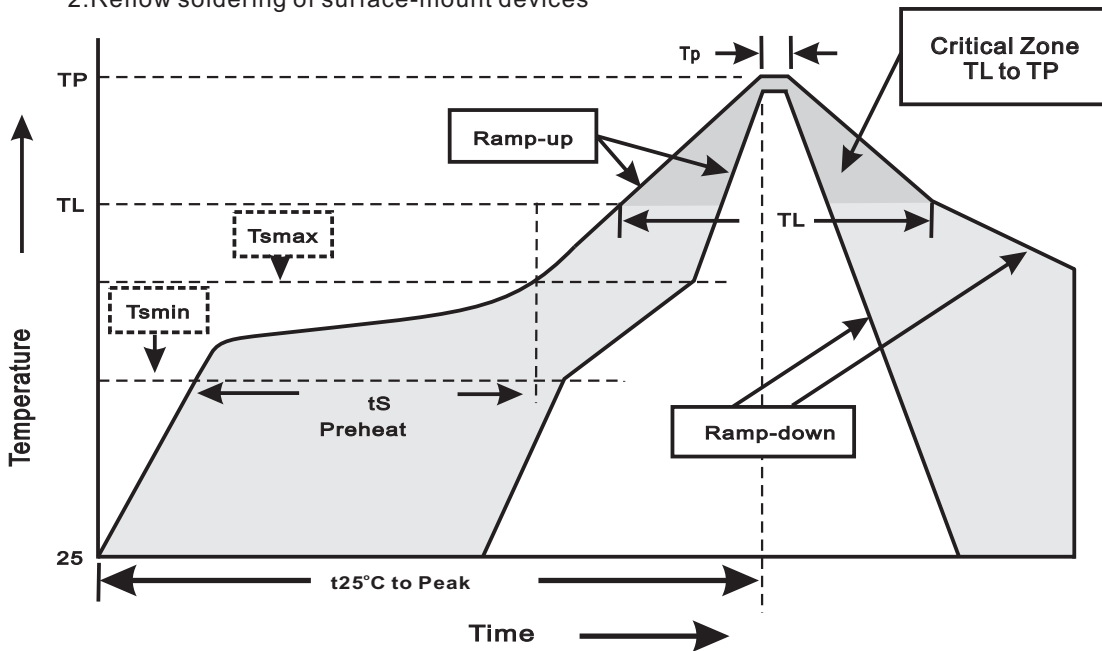
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Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
TO-277B	13"	5,000	8.0	10,000	337*337*37	330	350*330*360	80,000	18.0

Suggested thermal profiles for soldering processes

- 1.Storage environment: Temperature=5°C~40°C Humidity=55%±25%
- 2.Reflow soldering of surface-mount devices



3.Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate(T _L to T _P)	<3°C/sec
Preheat -Temperature Min(T _{smín}) -Temperature Max(T _{smáx}) -Time(min to max)(t _s)	150°C 200°C 60~120sec
T _{smáx} to T _L -Ramp-upRate	<3°C/sec
Time maintained above: -Temperature(T _L) -Time(t _L)	217°C 60~260sec
Peak Temperature(T _P)	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(t _P)	10~30sec
Ramp-down Rate	<3°C/sec
Time 25°C to Peak Temperature	<6minutes

FM10L45-T7B**High reliability test capabilities**

Item Test	Conditions	Reference
1. Solder Resistance	at $260\pm 5^{\circ}\text{C}$ for $10\pm 2\text{sec}$. immerse body into solder $1/16''\pm 1/32''$	MIL-STD-750D METHOD-2031
2. Solderability	at $245\pm 5^{\circ}\text{C}$ for 5 sec.	MIL-STD-202F METHOD-208
3. High Temperature Reverse Bias	$V_R=80\%$ rate at $T_J=150^{\circ}\text{C}$ for 168 hrs.	MIL-STD-750D METHOD-1038
4. Forward Operation Life	Rated average rectifier current at $T_A=25^{\circ}\text{C}$ for 500hrs.	MIL-STD-750D METHOD-1027
5. Intermittent Operation Life	$T_A = 25^{\circ}\text{C}$, $I_F = I_o$ On state: power on for 5 min. off state: power off for 5 min. on and off for 500 cycles.	MIL-STD-750D METHOD-1036
6. Pressure Cooker	$15P_{SIG}$ at $T_A=121^{\circ}\text{C}$ for 4 hrs.	JESD22-A102
7. Temperature Cycling	-55°C to $+125^{\circ}\text{C}$ dwelled for 30 min. and transferred for 5min. total 10 cycles.	MIL-STD-750D METHOD-1051
8. Forward Surge	8.3ms single half sine-wave , one surge.	MIL-STD-750D METHOD-4066-2
9. Humidity	at $T_A=85^{\circ}\text{C}$, RH=85% for 1000hrs.	MIL-STD-750D METHOD-1021
10. High Temperature Storage Life	at 175°C for 1000 hrs.	MIL-STD-750D METHOD-1031